

UTC UNISONIC TECHNOLOGIES CO., LTD

MMBTA55

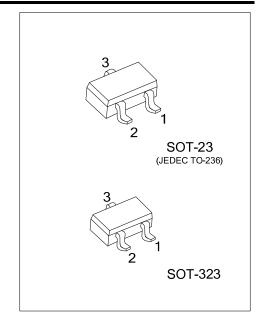
Preliminary

AMPLIFIER TRANSISTOR

PNP MMBTA55

FEATURES

* Collector-Emitter Voltage: V_{CEO}=60V



ORDERING INFORMATION

Ordering Number	Package	Pin Assignment			Dooking	
		1	2	3	Packing	
MMBTA55G-AE3-R	SOT-23	Е	В	С	Tape Reel	
MMBTA55G-AL3-R	SOT-323	E	В	С	Tape Reel	

Note: Pin Assignment: E: Emitter B: Base C: Collector MMBTA55G-AE3-R (1)Packing Type (1) R: Tape Reel (2)Package Type (2) AE3: SOT-23, AL3: SOT-323 (3)Green Package (3) G: Halogen Free and Lead Free

MARKING



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■ **ABSOLUTE MAXIMUM RATING** (T_A=25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT	
Collector-base voltage		V_{CBO}	60	V	
Collector-emitter voltage		V_{CEO}	60	V	
Emitter-base voltage		V_{EBO}	4	V	
Collector current - Continuous		I _C	500	mA	
Total device dissipation	T _A =25°C	- P _D	350	mW	
	Derate above 25°C		2.8	mW/°C	
Junction Temperature		TJ	125	°C	
Storage Temperature		T _{STG}	-40 ~ +150	°C	

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ THERMAL DATA

PARAMETER			UNIT	
Junction to Ambient	θ_{JA}	357	°C/W	

Note: $R_{\theta JA}$ is measured with the device soldered into a typical printed circuit board.

■ ELECTRICAL CHARACTERISTICS (T_A=25°C, unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT		
OFF CHARACTERISTICS								
Collector-emitter breakdown voltage (note 1)	$V_{(BR)CEO}$	I _C =1.0mA, I _B =0	60			V		
Emitter-base breakdown voltage	$V_{(BR)EBO}$	I _E =100μA, I _C =0	4			V		
Collector cutoff current	I _{CES}	V_{CE} =60V, I_{B} =0			0.1	μΑ		
Collector cutoff current	I _{CBO}	V_{CB} =60V, I_E =0			0.1	μΑ		
ON CHARACTERISTICS								
DC current gain	h _{FE}	I _C =10mA, V _{CE} =1V	100					
		I _C =100mA, V _{CE} =1V	100					
Collector-emitter saturation voltage	V _{CE(SAT)}	I _C =100mA, I _B =10mA			0.25	V		
Base-emitter on voltage	$V_{BE(ON)}$	I _C =100mA, V _{CE} =1V			1.2	V		
SMALL-SIGNAL CHARACTERISTICS								
Current gain bandwidth product (note 2)	f _T	I _C =100mA, V _{CE} =1V, f=100MHz	50			MHz		

Notes: 1. Pulse test: PW<=300μs, Duty Cycle<=2%

2. f_T is defined as the frequency at which lhfel extrapolates to unity.

■ SWITCHING TIME TEST CIRCUIT

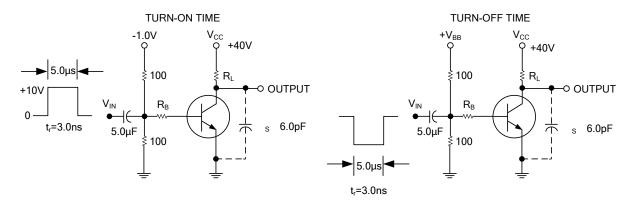


Figure 1. (Note: Total shunt capacitance of test jig and connectors for PNP test circuits, reverse all voltage polarities.)

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